

## MGBR10L120

Preliminary

DIODE

# DUAL MOS GATED BARRIER RECTIFIER

## DESCRIPTION

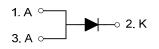
The UTC **MGBR10L120** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

## FEATURES

\* Low forward voltage drop

\* High switching speed

## SYMBOL

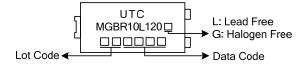


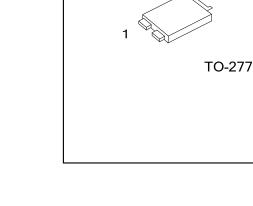
#### ORDERING INFORMATION

Ordering Number		Deelvage	Pin Assignment			Deaking	
Lead Free	Halogen Free	Halogen Free Package		2	3	Packing	
MGBR10L120L-T27-R MGBR10L120G-T27-R		TO-277	А	к	Α	Tape Reel	
Note: Pin Assignment: A: Anode K: Common Cathode							

MGBR10L120L-T27-R (1)Packing Type (2)Package Type (3)Green Package	<ul> <li>(1) R: Tape Reel</li> <li>(2) T27: TO-227</li> <li>(3) L: Lead Free, G: Halogen Free and Lead Free</li> </ul>
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## MARKING





### Preliminary

#### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

PARAMETER		SYMBOL	RATINGS	UNIT		
DC Blocking Voltage		V <sub>RM</sub>	120	V		
Working Peak Reverse Voltage		V <sub>RWM</sub>	120	V		
Peak Repetitive Reverse Voltage		V <sub>RRM</sub>	120	V		
Average Rectified Output Current	T <sub>C</sub> =125°C	lo	10	А		
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I <sub>FSM</sub>	160	А		
Operating Junction Temperature		TJ	-65~+150	°C		
Storage Temperature		T <sub>STG</sub>	-65~+150	°C		

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ <sub>JA</sub>	73	°C/W	
Junction to Case	θ <sub>JC</sub>	13	°C/W	

#### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> =25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V <sub>(BR)R</sub>	I <sub>R</sub> =0.50mA	120			V
Forward Voltage Drop		I <sub>F</sub> =10A, T <sub>J</sub> =25°C			0.82	V
		I <sub>F</sub> =10A, TJ=125°C			0.70	V
Leakage Current (Note 1)	I <sub>RM</sub>	V <sub>R</sub> =120V, T <sub>J</sub> =25°C			400	μA
		V <sub>R</sub> =120V, T <sub>J</sub> =125°C			30	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.



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